

- **Members of the Texas Instruments Widebus™ Family**
- **State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation**
- **Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)**
- **Support Unregulated Battery Operation Down to 2.7 V**
- **I<sub>off</sub> and Power-Up 3-State Support Hot Insertion**
- **Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors**
- **Typical V<sub>OLP</sub> (Output Ground Bounce) < 0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C**
- **Distributed V<sub>CC</sub> and GND Pin Configuration Minimizes High-Speed Switching Noise**
- **Flow-Through Architecture Optimizes PCB Layout**
- **Latch-Up Performance Exceeds 500 mA Per JESD 17**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Package Options Include Plastic Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings**

SN54LVTH16543 . . . WD PACKAGE  
 SN74LVTH16543 . . . DGG OR DL PACKAGE  
 (TOP VIEW)

1OEAB	1	56	1OEBA
1LEAB	2	55	1LEBA
1CEAB	3	54	1CEBA
GND	4	53	GND
1A1	5	52	1B1
1A2	6	51	1B2
V <sub>CC</sub>	7	50	V <sub>CC</sub>
1A3	8	49	1B3
1A4	9	48	1B4
1A5	10	47	1B5
GND	11	46	GND
1A6	12	45	1B6
1A7	13	44	1B7
1A8	14	43	1B8
2A1	15	42	2B1
2A2	16	41	2B2
2A3	17	40	2B3
GND	18	39	GND
2A4	19	38	2B4
2A5	20	37	2B5
2A6	21	36	2B6
V <sub>CC</sub>	22	35	V <sub>CC</sub>
2A7	23	34	2B7
2A8	24	33	2B8
GND	25	32	GND
2CEAB	26	31	2CEBA
2LEAB	27	30	2LEBA
2OEAB	28	29	2OEBA

## description

The 'LVTH16543 devices are 16-bit registered transceivers designed for low-voltage (3.3-V) V<sub>CC</sub> operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices can be used as two 8-bit transceivers or one 16-bit transceiver. Separate latch-enable (LEAB or LEBA) and output-enable (OEAB or OEBA) inputs are provided for each register to permit independent control in either direction of data flow.

The A-to-B enable (CEAB) input must be low to enter data from A or to output data from B. If CEAB is low and LEAB is low, the A-to-B latches are transparent; a subsequent low-to-high transition of LEAB puts the A latches in the storage mode. With CEAB and OEAB both low, the 3-state B outputs are active and reflect the data present at the output of the A latches. Data flow from B to A is similar but requires using the CEBA, LEBA, and OEBA inputs.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.



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**SN54LVTH16543, SN74LVTH16543  
3.3-V ABT 16-BIT REGISTERED TRANSCEIVERS  
WITH 3-STATE OUTPUTS**

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**description (continued)**

When  $V_{CC}$  is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

The SN54LVTH16543 is characterized for operation over the full military temperature range of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The SN74LVTH16543 is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

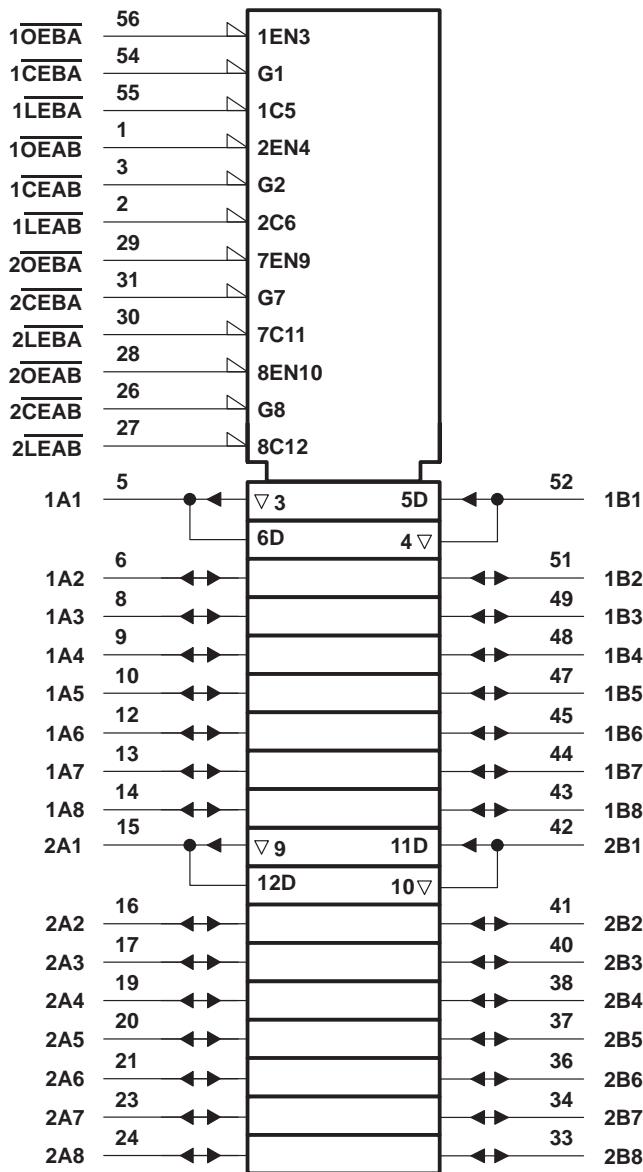
**FUNCTION TABLE†  
(each 8-bit section)**

INPUTS				OUTPUT B
CEAB	LEAB	$\overline{OEAB}$	A	
H	X	X	X	Z
X	X	H	X	Z
L	H	L	X	$B_0^{\ddagger}$
L	L	L	L	L
L	L	L	H	H

† A-to-B data flow is shown; B-to-A flow control is the same except that it uses CEBA, LEBA, and  $\overline{OEBA}$ .

‡ Output level before the indicated steady-state input conditions were established

logic symbol†

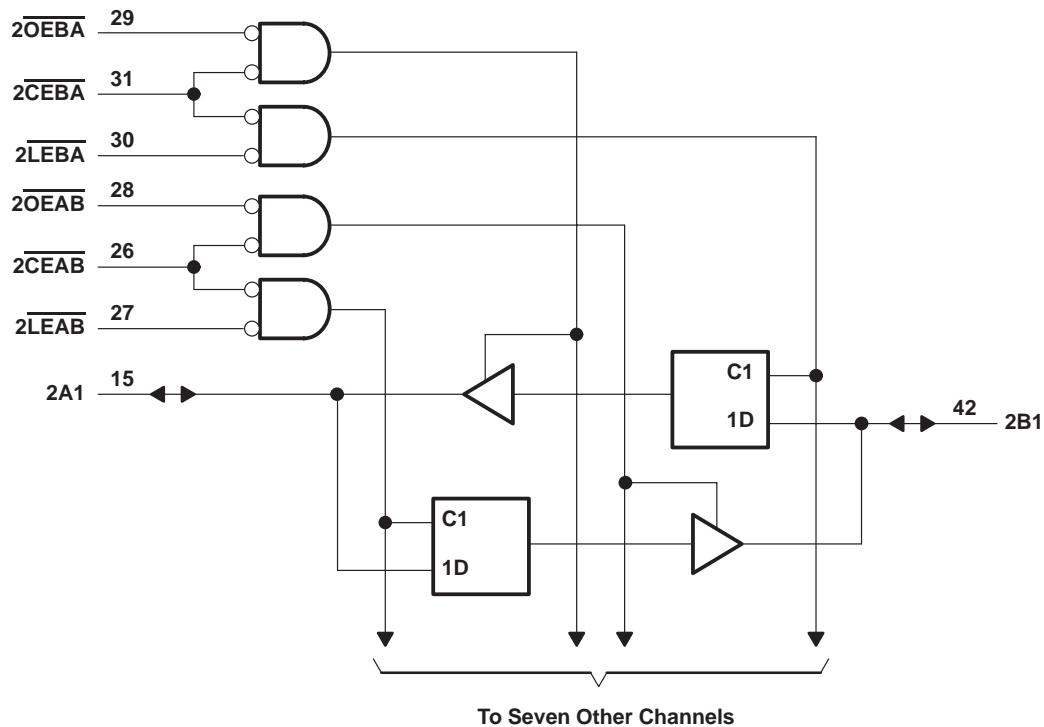
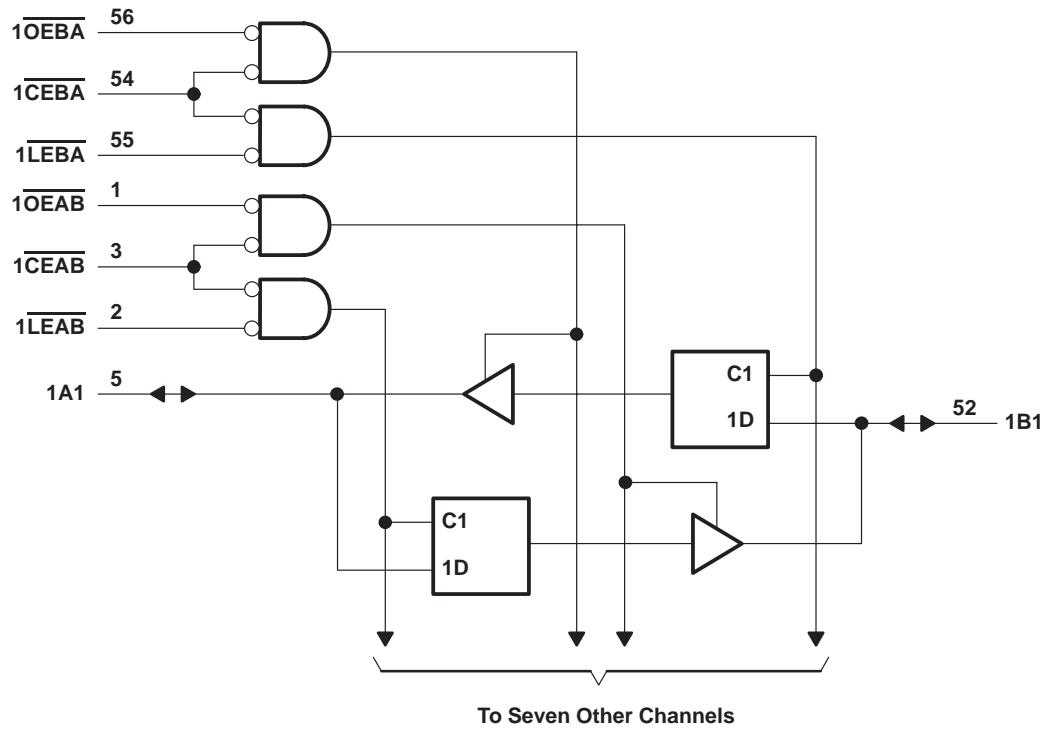


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

# **SN54LVTH16543, SN74LVTH16543 3.3-V ABT 16-BIT REGISTERED TRANSCEIVERS WITH 3-STATE OUTPUTS**

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## logic diagram (positive logic)



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**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)**

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This current flows only when the output is in the high state and  $V_O > V_{CC}$ .
3. The package thermal impedance is calculated in accordance with JESD 51.

#### **recommended operating conditions (see Note 4)**

		SN54LVTH16543		SN74LVTH16543		UNIT	
		MIN	MAX	MIN	MAX		
V <sub>CC</sub>	Supply voltage	2.7	3.6	2.7	3.6	V	
V <sub>IH</sub>	High-level input voltage	2		2		V	
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V	
V <sub>I</sub>	Input voltage		5.5		5.5	V	
I <sub>OH</sub>	High-level output current		-24		-32	mA	
I <sub>OL</sub>	Low-level output current		48		64	mA	
Δt/Δv	Input transition rise or fall rate	Outputs enabled		10	10	ns/V	
Δt/ΔV <sub>CC</sub>	Power-up ramp rate		200	200		μs/V	
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	SN54LVTH16543			SN74LVTH16543			UNIT
		MIN	TYP†	MAX	MIN	TYP†	MAX	
$V_{IK}$	$V_{CC} = 2.7 \text{ V}$ , $I_I = -18 \text{ mA}$			-1.2			-1.2	V
$V_{OH}$	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ , $I_{OH} = -100 \mu\text{A}$	$V_{CC} - 0.2$			$V_{CC} - 0.2$			V
	$V_{CC} = 2.7 \text{ V}$ , $I_{OH} = -8 \text{ mA}$	2.4			2.4			
	$V_{CC} = 3 \text{ V}$	$I_{OH} = -24 \text{ mA}$	2				2	
		$I_{OH} = -32 \text{ mA}$						
$V_{OL}$	$V_{CC} = 2.7 \text{ V}$	$I_{OL} = 100 \mu\text{A}$		0.2			0.2	V
		$I_{OL} = 24 \text{ mA}$		0.5			0.5	
	$V_{CC} = 3 \text{ V}$	$I_{OL} = 16 \text{ mA}$		0.4			0.4	
		$I_{OL} = 32 \text{ mA}$		0.5			0.5	
		$I_{OL} = 48 \text{ mA}$		0.55				
		$I_{OL} = 64 \text{ mA}$					0.55	
$I_I$	Control inputs	$V_{CC} = 3.6 \text{ V}$ , $V_I = V_{CC}$ or GND		$\pm 1$			$\pm 1$	$\mu\text{A}$
		$V_{CC} = 0$ or $3.6 \text{ V}$ , $V_I = 5.5 \text{ V}$		10			10	
	A or B ports‡	$V_{CC} = 3.6 \text{ V}$	$V_I = 5.5 \text{ V}$	20			20	
			$V_I = V_{CC}$	1			1	
		$V_{CC} = 3.6 \text{ V} \S$	$V_I = 0$	-5			-5	
$I_{off}$	$V_{CC} = 0$ , $V_I$ or $V_O = 0$ to $4.5 \text{ V}$						$\pm 100$	$\mu\text{A}$
$I_I$ (hold)	A or B ports	$V_{CC} = 3 \text{ V}$	$V_I = 0.8 \text{ V}$	75			75	$\mu\text{A}$
			$V_I = 2 \text{ V}$	-75			-75	
		$V_{CC} = 3.6 \text{ V} \S$	$V_I = 0$ to $3.6 \text{ V}$				$\pm 500$	
$I_{OZPU}$	$V_{CC} = 0$ to $1.5 \text{ V}$ , $V_O = 0.5 \text{ V}$ to $3 \text{ V}$ , $OE$ = don't care			$\pm 100^*$			$\pm 100$	$\mu\text{A}$
$I_{OZPD}$	$V_{CC} = 1.5 \text{ V}$ to $0$ , $V_O = 0.5 \text{ V}$ to $3 \text{ V}$ , $OE$ = don't care			$\pm 100^*$			$\pm 100$	$\mu\text{A}$
$I_{CC}$	$V_{CC} = 3.6 \text{ V}$ , $I_O = 0$ , $V_I = V_{CC}$ or GND	Outputs high		0.19			0.19	$\text{mA}$
		Outputs low		5			5	
		Outputs disabled		0.19			0.19	
$\Delta I_{CC} \dagger$	$V_{CC} = 3 \text{ V}$ to $3.6 \text{ V}$ , One input at $V_{CC} - 0.6 \text{ V}$ , Other inputs at $V_{CC}$ or GND			0.2			0.2	$\text{mA}$
$C_i$	$V_I = 3 \text{ V}$ or $0$			4			4	$\text{pF}$
$C_{io}$	$V_O = 3 \text{ V}$ or $0$			10			10	$\text{pF}$

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.

† All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

‡ Unused pins at  $V_{CC}$  or GND

§ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than  $V_{CC}$  or GND.

PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas Instruments reserves the right to change or discontinue these products without notice.



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**WITH 3-STATE OUTPUTS**

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**timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)**

			SN54LVTH16543		SN74LVTH16543		UNIT	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		$V_{CC} = 2.7 \text{ V}$			
			MIN	MAX	MIN	MAX		
$t_W$ Pulse duration, LEAB or LEBA low			3.3	3.3	3.3	3.3	ns	
$t_{SU}$ Setup time	A or B before LEAB↑ or LEBA↑	Data high	0.5	0.5	0.5	0.5	ns	
		Data low	0.8	1.3	0.8	1.3		
	A or B before CEAB↑ or CEBA↑	Data high	0	0	0	0		
		Data low	0.6	1.1	0.6	1.1		
$t_H$ Hold time	A or B after LEAB↑ or LEBA↑	Data high	1.5	0.7	1.5	0.7	ns	
		Data low	1.2	1.3	1.2	1.3		
	A or B after CEAB↑ or CEBA↑	Data high	1.7	0.9	1.7	0.9		
		Data low	1.6	1.8	1.6	1.8		

**switching characteristics over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVTH16543		SN74LVTH16543		UNIT		
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$				
			MIN	MAX	MIN	MAX			
$t_{PLH}$	A or B	B or A	1.1	3.4	3.9	1.2	2.3	3.2	ns
			1.1	3.4	3.9	1.2	2.1	3.2	
$t_{PHL}$	$\overline{LE}$	A or B	1.2	4.1	5.1	1.3	2.5	3.9	ns
			1.2	4.1	5.1	1.3	2.3	3.9	
$t_{PZH}$	$\overline{OE}$	A or B	1.2	4.5	5.6	1.3	2.8	4.3	ns
			1.2	4.5	5.6	1.3	2.8	4.3	
$t_{PZL}$	$\overline{OE}$	A or B	1.9	4.9	5.4	2	3.5	4.7	ns
			1.9	4.6	4.7	2	3.3	4.4	
$t_{PHZ}$	$\overline{OE}$	A or B	1.2	4.7	5.8	1.3	3	4.5	ns
			1.2	4.7	5.8	1.3	3	4.5	
$t_{PZL}$	$\overline{CE}$	A or B	1.9	5.1	5.6	2	3.6	4.9	ns
			1.9	4.9	5.1	2	3.5	4.7	

† All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

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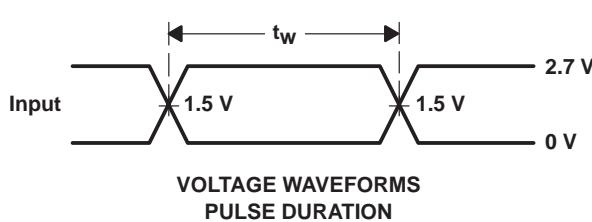
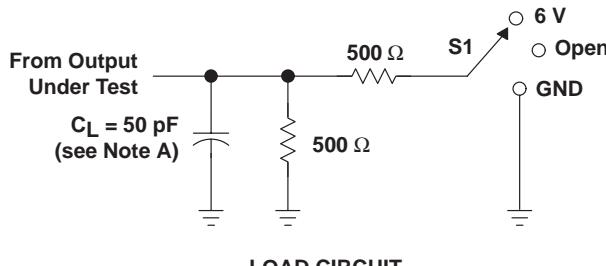


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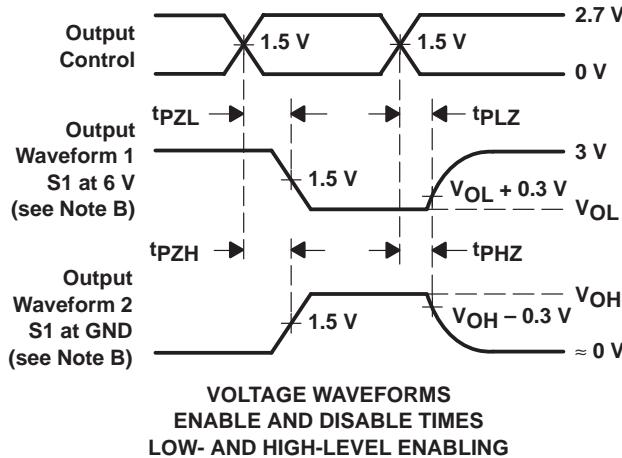
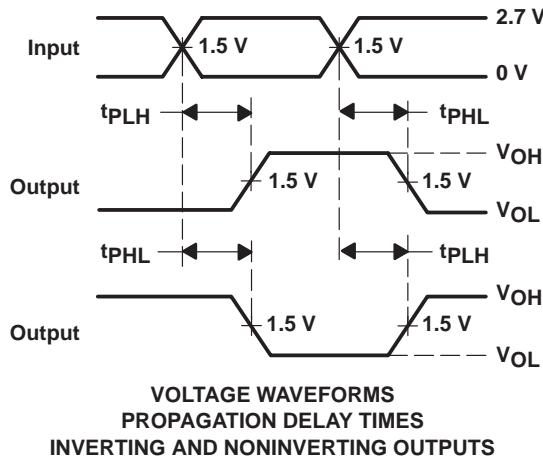
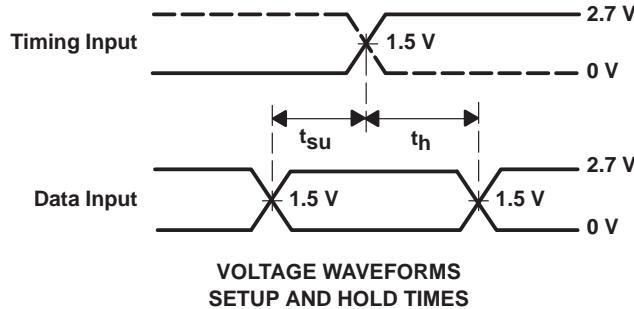
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**PARAMETER MEASUREMENT INFORMATION**



TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	6 V
$t_{PHZ}/t_{PZH}$	GND



NOTES:

- $C_L$  includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR  $\leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2.5 \text{ ns}$ ,  $t_f \leq 2.5 \text{ ns}$ .
- The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
74LVTH16543DGGRG4	Active	Production	TSSOP (DGG)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16543
74LVTH16543DGGRG4.B	Active	Production	TSSOP (DGG)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16543
<a href="#">SN74LVTH16543DGGR</a>	Active	Production	TSSOP (DGG)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16543
SN74LVTH16543DGGR.B	Active	Production	TSSOP (DGG)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16543
<a href="#">SN74LVTH16543DL</a>	Active	Production	SSOP (DL)   56	20   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16543
SN74LVTH16543DL.B	Active	Production	SSOP (DL)   56	20   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16543
<a href="#">SN74LVTH16543DLR</a>	Active	Production	SSOP (DL)   56	1000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16543
SN74LVTH16543DLR.B	Active	Production	SSOP (DL)   56	1000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH16543

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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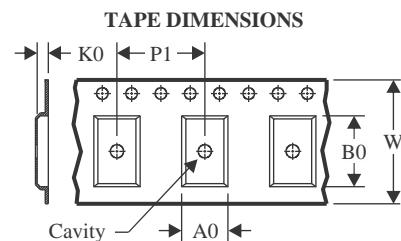
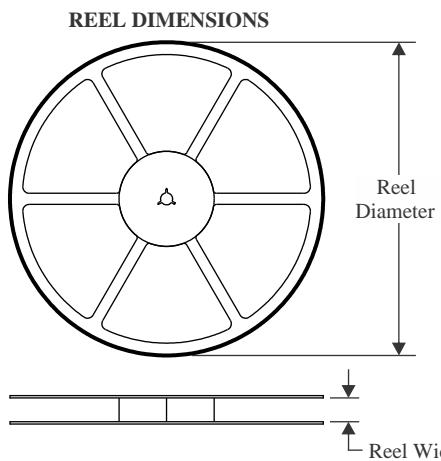
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**OTHER QUALIFIED VERSIONS OF SN74LVTH16543 :**

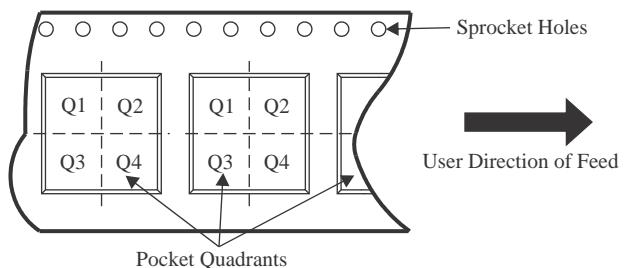
- Enhanced Product : [SN74LVTH16543-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

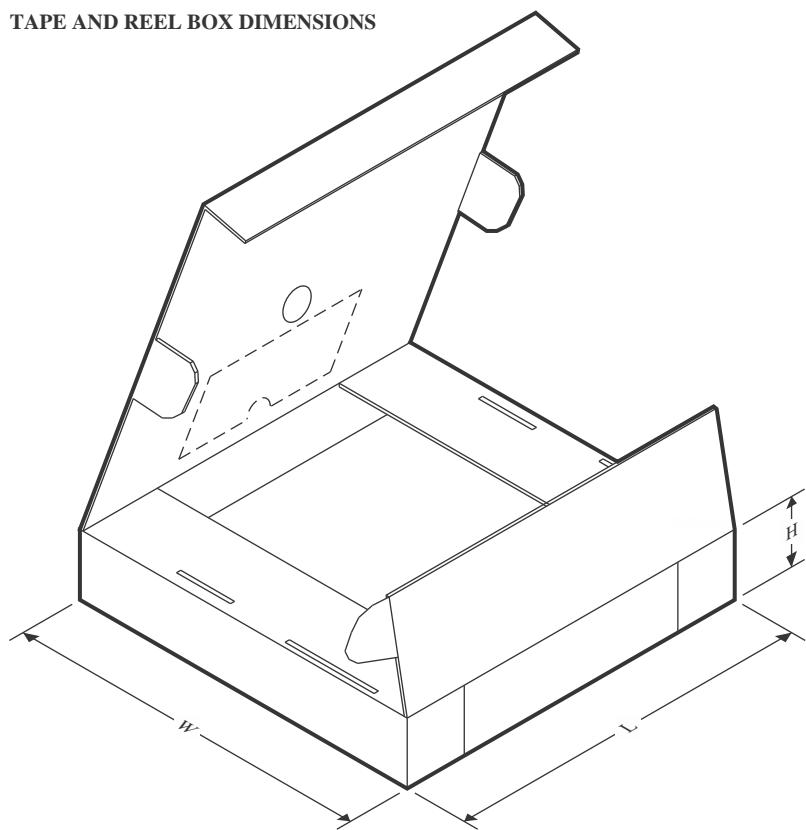
**TAPE AND REEL INFORMATION**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


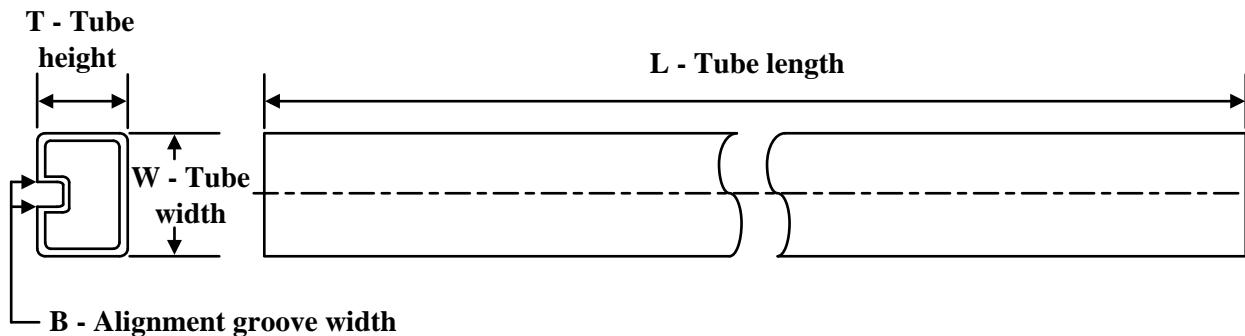
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74LVTH16543DGGRG4	TSSOP	DGG	56	2000	330.0	24.4	8.9	14.7	1.4	12.0	24.0	Q1
SN74LVTH16543DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.9	14.7	1.4	12.0	24.0	Q1
SN74LVTH16543DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74LVTH16543DGGRG4	TSSOP	DGG	56	2000	356.0	356.0	45.0
SN74LVTH16543DGGR	TSSOP	DGG	56	2000	356.0	356.0	45.0
SN74LVTH16543DLR	SSOP	DL	56	1000	356.0	356.0	53.0

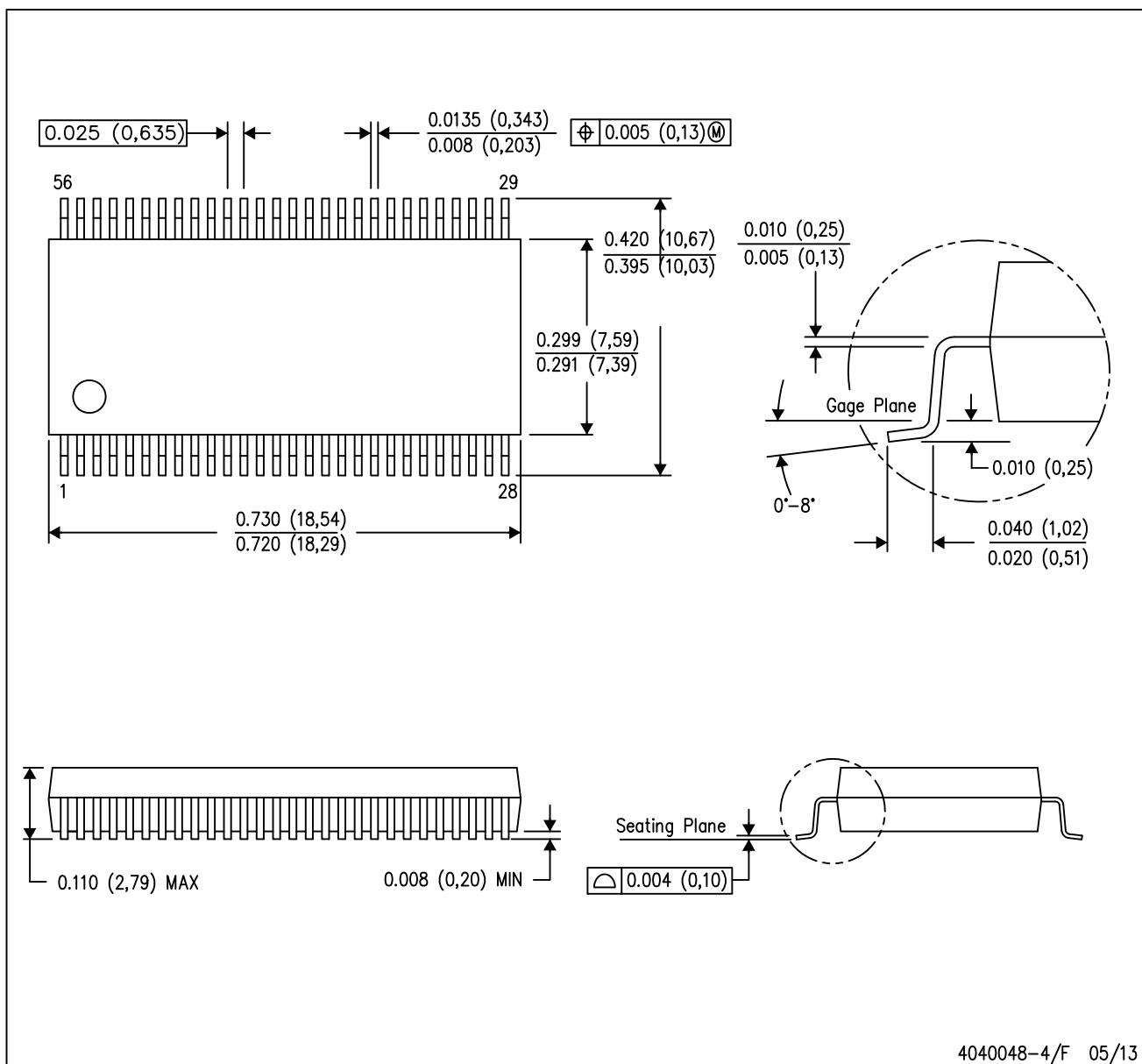
**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T ( $\mu$ m)	B (mm)
SN74LVTH16543DL	DL	SSOP	56	20	473.7	14.24	5110	7.87
SN74LVTH16543DL.B	DL	SSOP	56	20	473.7	14.24	5110	7.87

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.

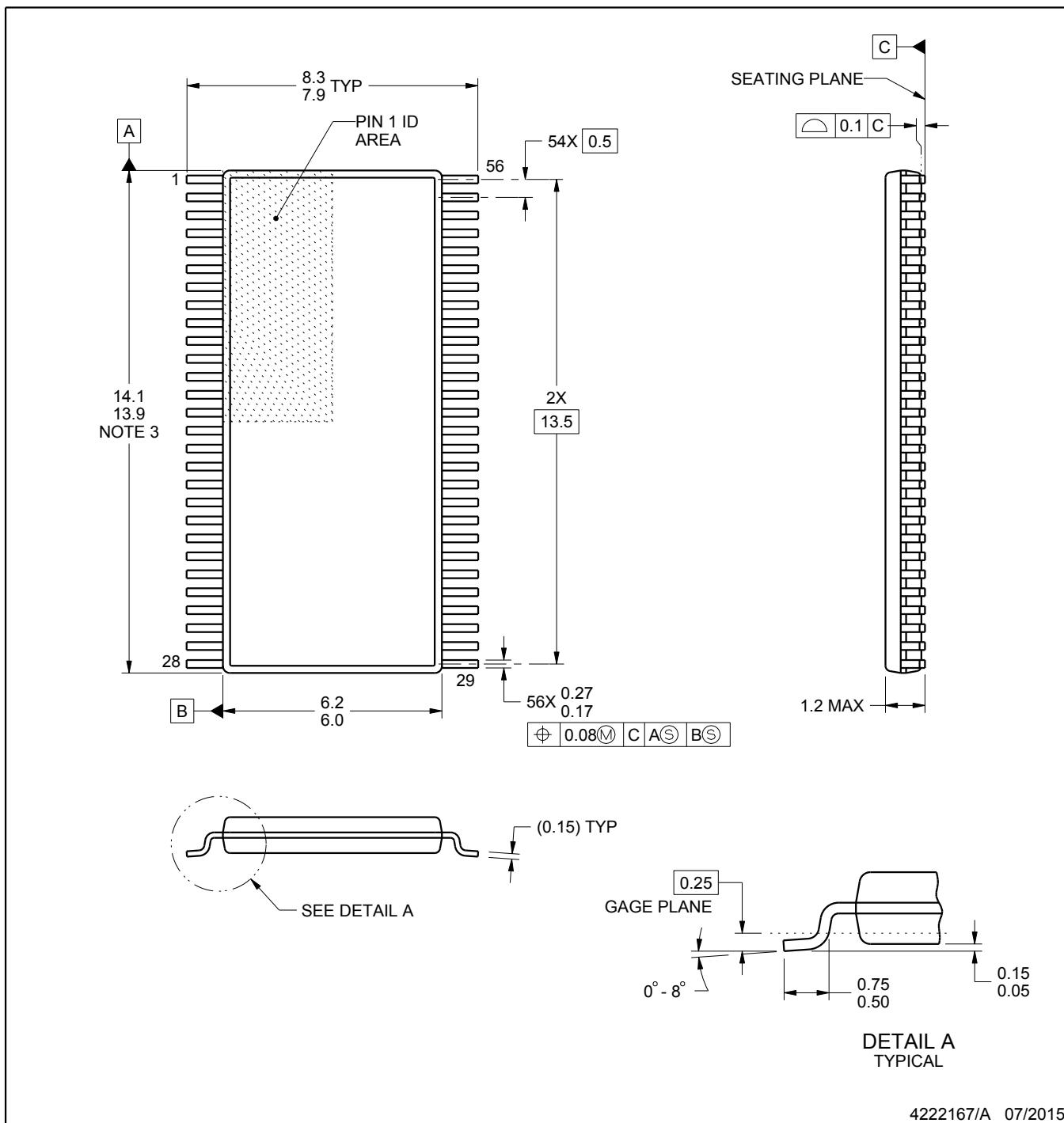
# PACKAGE OUTLINE

DGG0056A



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

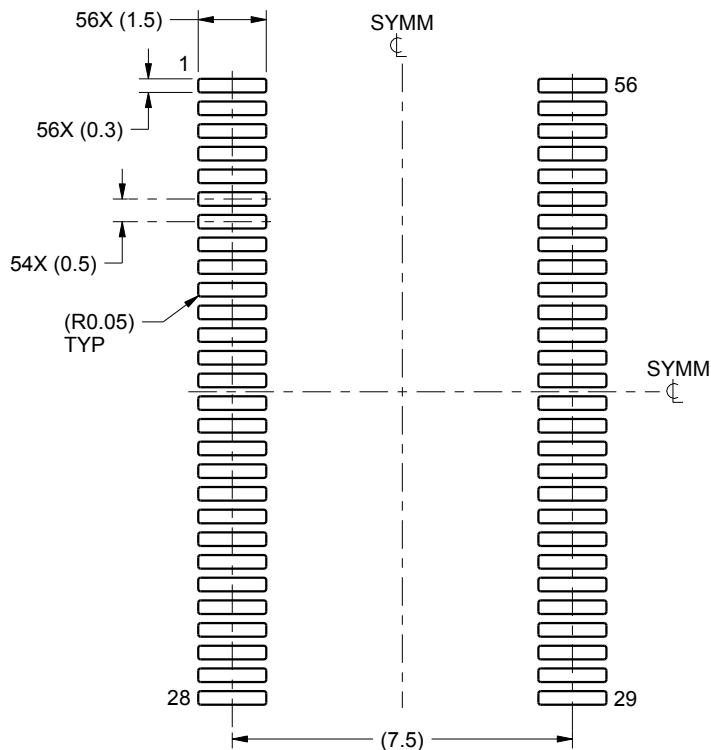
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

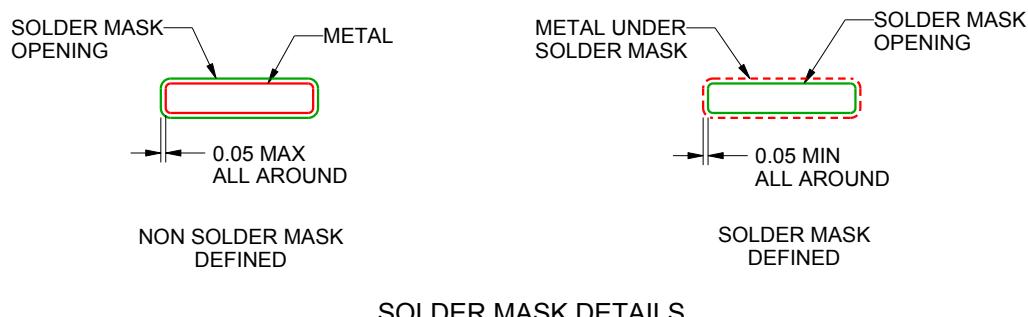
DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:6X



SOLDER MASK DETAILS

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NOTES: (continued)

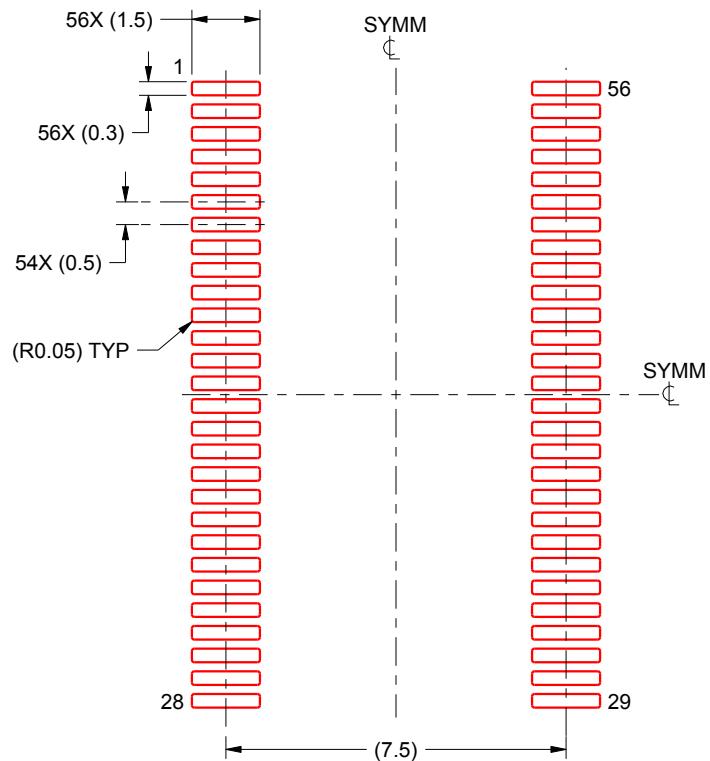
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:6X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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